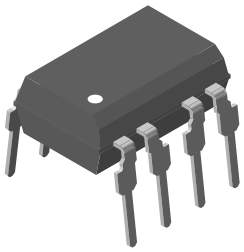
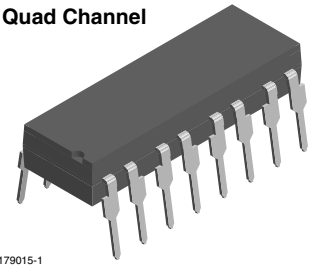
Optocoupler, Phototransistor Output, (Dual, Quad Channel), 110 °C Rated

Dual Channel



Quad Channel



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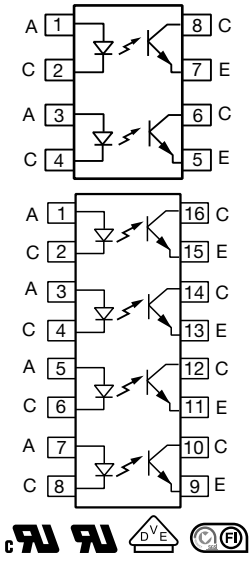


DESCRIPTION

The ILD1615, ILQ1615 are multi-channel 110 °C rated phototransistor optocouplers that use GaAs IRLED emitters and high gain NPN phototransistors. These devices are constructed using over/under leadframe optical coupling and double molded insulation technology resulting a withstand test voltage of 7500 $V_{AC\ PEAK}$ and a working voltage of 1700 V_{RMS}.

The binned min. / max. and linear CTR characteristics make these devices well suited for DC or AC voltage detection. Eliminating the phototransistor base connection provides added electrical noise immunity from the transients found in many industrial control environments.

Because of guaranteed maximum non-saturated and saturated switching characteristics, the ILD1615, ILQ1615 can be used in medium speed data I/O and control systems. The binned min. / max. CTR specification allow easy worst case interface calculations for both level detection and switching applications. Interfacing with a CMOS logic is enhanced by the guaranteed CTR at I_F = 1.0 mA.

FEATURES

- Operating temperature from -55 °C to +110 °C
- Identical channel to channel footprint
- Dual and quad packages feature:
  - Reduced board space
  - Lower pin and parts count
  - Better channel to channel CTR match
  - Improved common mode rejection
- Isolation test voltage, 5300 V_{RMS}
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

e3

RoHS COMPLIANT

AGENCY APPROVALS

- UL 1577
- cUL
- DIN EN 60747-5-5 (VDE 0884), available with option 1
- FIMKO

LINKS TO ADDITIONAL RESOURCES

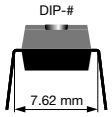
Product Page

ORDERING INFORMATION

I	L	x	1	6	1	5	-	4

PART NUMBER
x = D (Dual) or Q (Quad)

CTR BIN



AGENCY CERTIFIED / PACKAGE	DUAL CHANNEL	QUAD CHANNEL
	CTR (%)	
UL, cUL, FIMKO	**160 to 320**	**160 to 320**
DIP-8	ILD1615-4	-
DIP-16	-	ILQ1615-4

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Peak reverse voltage		V_R	6.0	V
Forward current		I_F	60	mA
Surge current		I_{FSM}	1.5	A
Power dissipation		P_{diss}	100	mW
Derate linearly from 25 °C			1.0	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV_{CEO}	70	V
Emitter collector breakdown voltage		BV_{ECO}	7.0	V
Collector current		I_C	50	mA
	t < 1.0 ms	I_C	100	mA
Power dissipation		P_{diss}	150	mW
Derate linearly from 25 °C			1.5	mW/°C
COUPLER				
Storage temperature		T_{stg}	-55 to +150	°C
Operating temperature		T_{amb}	-55 to +110	°C
Soldering temperature [1]	2.0 mm distance from case bottom	T_{sld}	260	°C
Package power dissipation ILD1615			400	mW
Derate linearly from 25 °C			5.33	mW/°C
Package power dissipation ILQ1615			500	mW
Derate linearly from 25 °C			6.67	mW/°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(1) Refer to wave profile for soldering conditions for through hole devices

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
INPUT						
Forward voltage	I_F = 10 mA	V_F	1.0	1.15	1.3	V
Breakdown voltage	I_R = 10 µA	V_{BR}	6.0	30	-	V
Reverse current	V_R = 6.0 V	I_R	-	0.01	10	µA
Capacitance	V_R = 0 V, f = 1.0 MHz	C_O	-	25	-	pF
OUTPUT						
Collector emitter capacitance	V_{CE} = 5.0 V, f = 1.0 MHz	C_{CE}	-	6.8	-	pF
Collector emitter leakage current	V_{CE} = 10 V	I_{CEO}	-	5.0	100	nA
Collector emitter breakdown voltage	I_{CE} = 0.5 mA	BV_{CEO}	70	-	-	V
Emitter collector breakdown voltage	I_E = 0.1 mA	BV_{ECO}	7.0	-	-	V
PACKAGE TRANSFER CHARACTERISTICS						
Channel/channel CTR match	I_F = 10 mA, V_{CE} = 5.0 V	CTRX/CTRY	1 to 1	-	2 to 1	
COUPLER						
Capacitance (input to output)	V_{IO} = 0 V, f = 1.0 MHz	C_{IO}	-	0.8	-	pF
Insulation resistance	V_{IO} = 500 V, T_A = 25 °C	R_S	10^{12}	10^{14}	-	Ω
Channel to channel isolation			500	-	-	V_{AC}

Note

- Minimum and maximum values are tested requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Current transfer ratio (collector emitter saturated)	I_F = 1.0 mA, V_{CE} = 0.4 V	ILD1615-4 ILQ1615-4	CTR_{CEsat}	-	100	-	%
Current transfer ratio (collector emitter)	I_F = 10 mA, V_{CE} = 5.0 V	ILD1615-4 ILQ1615-4	CTR_{CE}	160	200	320	%
	I_F = 1.0 mA, V_{CE} = 5.0 V	ILD1615-4 ILQ1615-4	CTR_{CE}	56	90	-	%

SWITCHING CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
NON-SATURATED						
Turn-on time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω, 50 % of V_{PP}	t_{on}	-	3.0	-	µs
Rise time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω, 50 % of V_{PP}	t_r	-	2.0	-	µs
Turn-off time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω, 50 % of V_{PP}	t_{off}	-	2.3	-	µs
Fall time	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω, 50 % of V_{PP}	t_f	-	2.0	-	µs
Propagation H to L	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω, 50 % of V_{PP}	t_{PHL}	-	1.1	-	µs
Propagation L to H	I_F = 10 mA, V_{CC} = 5.0 V, R_L = 75 Ω, 50 % of V_{PP}	t_{PLH}	-	2.5	-	µs
SATURATED						
Turn-on time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 kΩ, V_{HT} = 1.5 V	t_{on}	-	6.0	-	µs
Rise time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 kΩ, V_{HT} = 1.5 V	t_r	-	4.6	-	µs
Turn-off time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 kΩ, V_{HT} = 1.5 V	t_{off}	-	25	-	µs
Fall time	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 kΩ, V_{HT} = 1.5 V	t_f	-	15	-	µs
Propagation H to L	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 kΩ, V_{HT} = 1.5 V	t_{PHL}	-	5.4	-	µs
Propagation L to H	I_F = 5.0 mA, V_{CC} = 5.0 V, R_L = 1.0 kΩ, V_{HT} = 1.5 V	t_{PLH}	-	7.4	-	µs

COMMON MODE TRANSIENT IMMUNITY (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Common mode rejection output high	V_{CM} = 50 V_{P-P}, R_L = 1.0 kΩ, I_F = 0 mA	CM_H	-	5000	-	V/µs
Common mode rejection output low	V_{CM} = 50 V_{P-P}, R_L = 1.0 kΩ, I_F = 10 mA	CM_L	-	5000	-	V/µs
Common mode coupling capacitance		C_{CM}	-	0.01	-	pF

SAFETY AND INSULATION RATINGS				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
Climatic classification	According to IEC 68 part 1		55 / 110 / 21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	t = 1 min	V_{ISO}	4420	V_{RMS}
Maximum transient isolation voltage		V_{IOTM}	10 000	V_{peak}
Maximum repetitive peak isolation voltage		V_{IORM}	890	V_{peak}
Isolation resistance	V_{IO} = 500 V, T_{amb} = 25 °C	R_{IO}	$\geq 10^{12}$	Ω
	V_{IO} = 500 V, T_{amb} = 100 °C	R_{IO}	$\geq 10^{11}$	Ω
Output safety power		P_{SO}	400	mW
Input safety current		I_{SI}	275	mA
Safety temperature		T_S	175	°C
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

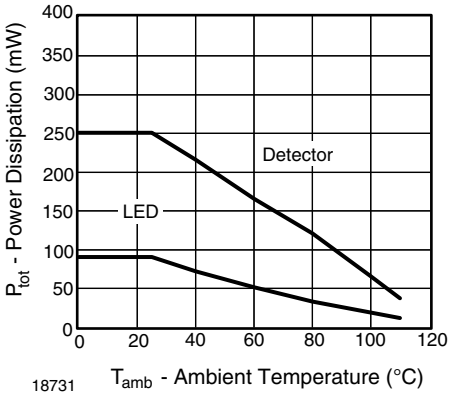


Fig. 1 - Permissible Power Dissipation vs. Temperature Non-Saturation Operation

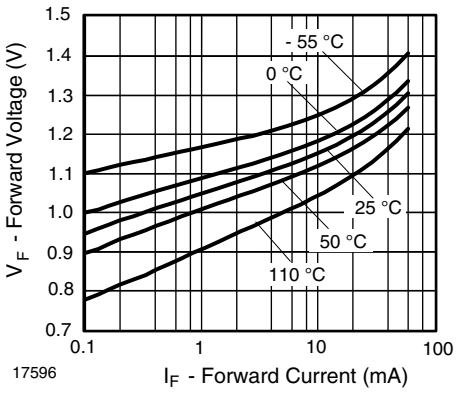


Fig. 2 - Forward Voltage vs. Forward Current

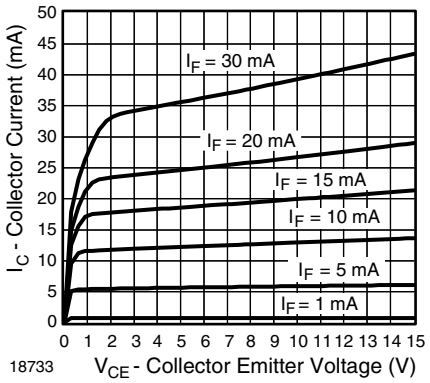


Fig. 3 - Collector Current vs. Collector Emitter Voltage

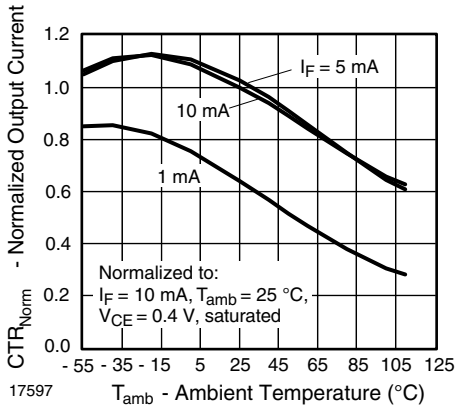


Fig. 6 - Normalized Current Transfer Ratio vs. Ambient Temperature

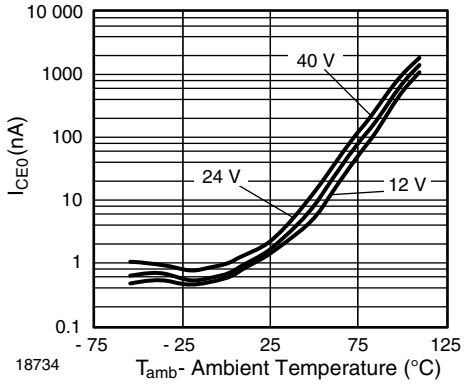


Fig. 4 - Collector to Emitter Dark Current vs. Ambient Temperature

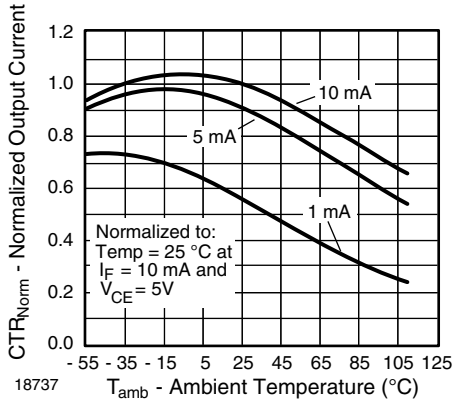


Fig. 7 - Normalized CTR vs. Temperature

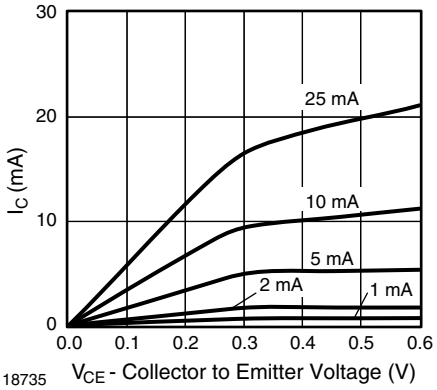


Fig. 5 - Normalized Current vs. Collector Emitter Saturation Voltage

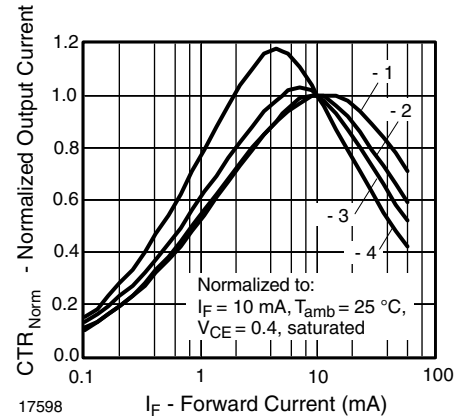


Fig. 8 - Normalized CTR vs. Forward Current

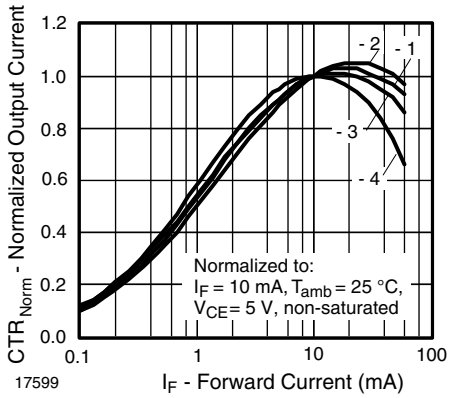


Fig. 9 - Normalized CTR vs. Forward Current

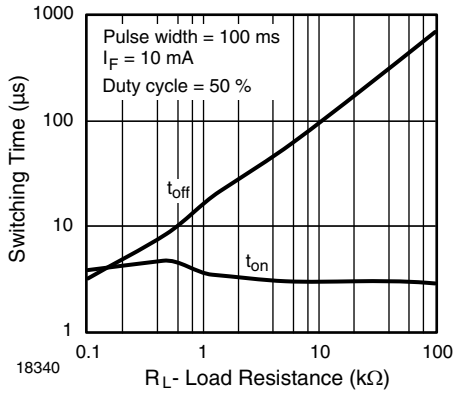


Fig. 10 - Forward Resistance vs. Forward Current

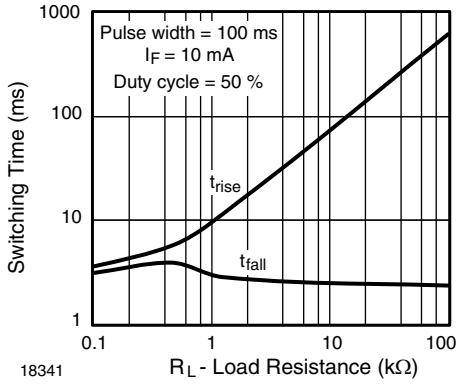
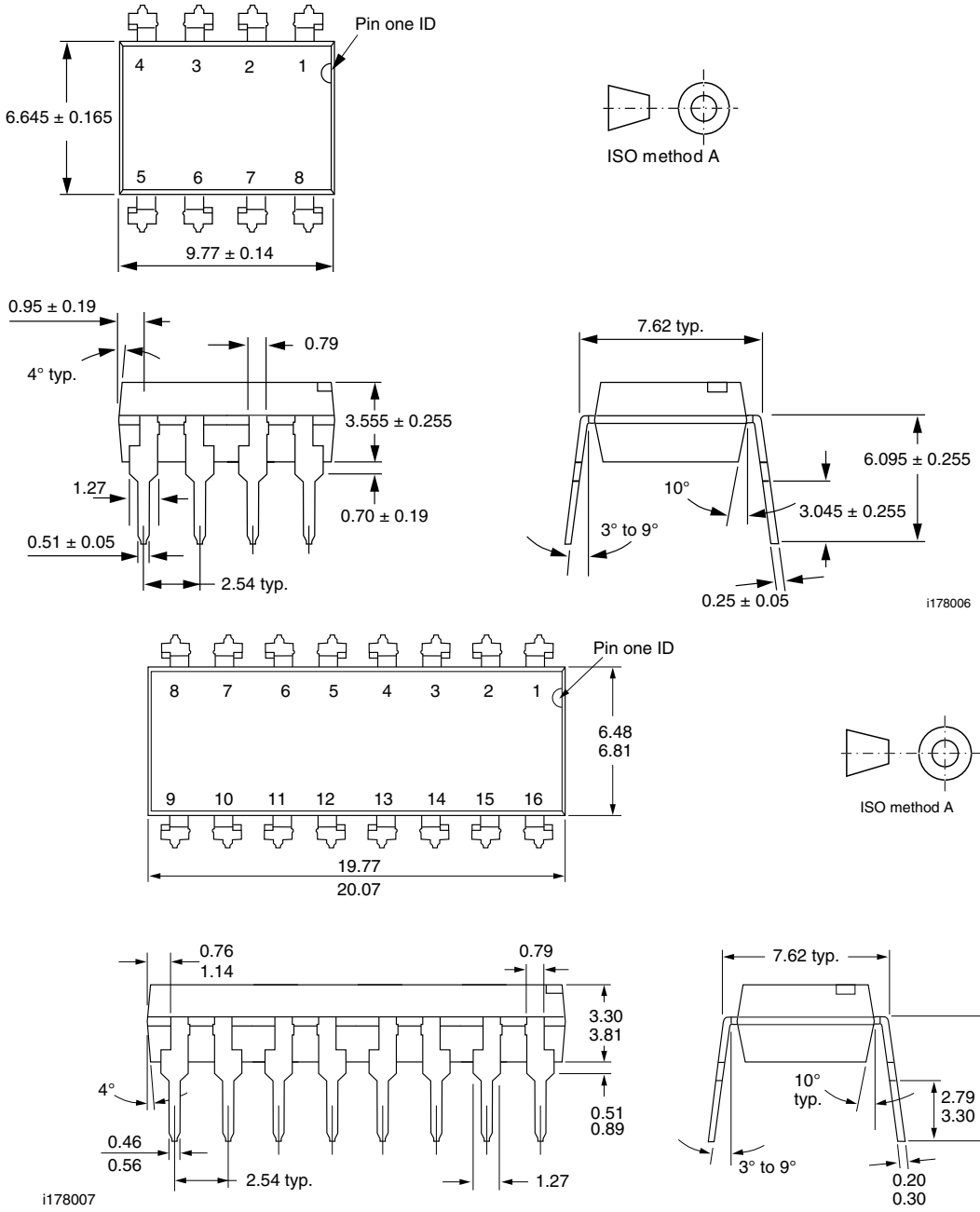


Fig. 11 - Forward Resistance vs. Forward Current

PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING

Note

- XXXX = LMC (lot marking code)

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